

Application No.: 10/678,766  
Filing Date: October 2, 2003

## SUMMARY OF INTERVIEW

### Attendees, Date and Type of Interview

The interview was conducted on May 14, 2010 and attended by Examiner Matthew Song and Applicant's representatives Adeel Akhtar and David Buckingham.

### Exhibits and/or Demonstrations

None

### Identification of Claims Discussed

Pending claims

### Identification of Prior Art Discussed

The cited references, including "Surface Chemistry for Atomic Layer Growth" by George et al.

### Proposed Amendments

None

### Principal Arguments and Other Matters

Applicant argued that the  $\text{SiCl}_4$  of George does not work to produce silicon oxide in a flow-through reactor as stated in the Declaration. Applicant also argued that the fact that the process worked was surprising and the high growth rate in comparison to the individual metal oxide and silicon oxide processes was unexpected. Applicants also pointed out to the Examiner that the facts presented in the Declarations cannot be disregarded without any evidence to the contrary.

### Results of Interview

The Examiner agreed to consider Applicant's arguments in a written reply.